

**SCHOTTKY BARRIER RECTIFIERS**

**VOLTAGE RANGE: 30 - 100 V  
CURRENT: 15 A**

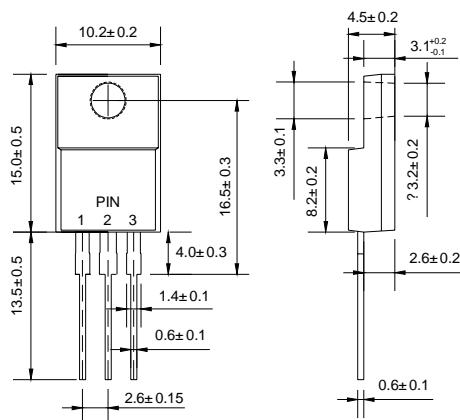
**FEATURES**

- ◇ High surge capacity.
- ◇ For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications.
- ◇ Metal silicon junction, majority carrier conduction.
- ◇ High current capacity, low forward voltage drop.
- ◇ Guard ring for over voltage protection.

**MECHANICAL DATA**

- ◇ Case: JEDEC ITO-220AB, molded plastic body
- ◇ Terminals: Solderable per MIL-STD-750, Method 2026
- ◇ Polarity: As marked
- ◇ Position: Any
- ◇ Weight: 0.06ounce, 1.67 grams

**ITO-220AB**



Dimensions in millimeters

**MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS**

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

		MBRF 1530CT	MBRF 1535CT	MBRF 1540CT	MBRF 1545CT	MBRF 1550CT	MBRF 1560CT	MBRF 1580CT	MBRF 15100CT	UNITS						
Maximum recurrent peak reverse voltage	$V_{RRM}$	30	35	40	45	50	60	80	100	V						
Maximum RMS Voltage	$V_{RMS}$	21	25	28	32	35	42	56	70	V						
Maximum DC blocking voltage	$V_{DC}$	30	35	40	45	50	60	80	100	V						
Maximum average forward total device rectified current @ $T_c = 105^\circ C$	$I_{F(AV)}$	15								A						
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load	$I_{FSM}$	150								A						
Maximum forward voltage (I <sub>F</sub> =7.5A, T <sub>c</sub> =25°C) (I <sub>F</sub> =7.5A, T <sub>c</sub> =125°C) (Note 1) (I <sub>F</sub> =15A, T <sub>c</sub> =25°C) (I <sub>F</sub> =15A, T <sub>c</sub> =125°C)	$V_F$	-		0.57		0.75		0.80		V						
0.84		0.65		-		-		-								
0.72		-		-		-		-								
Maximum reverse current @ $T_c = 25^\circ C$ at rated DC blocking voltage @ $T_c = 125^\circ C$	$I_R$	0.1		1.0		0.1		m A								
		15		50		6.0 <sup>3)</sup>										
Maximum thermal resistance (Note 2)	$R_{\theta JC}$	3.0								°C/W						
Operating junction temperature range	$T_J$	- 55 ---- + 150								°C						
Storage temperature range	$T_{STG}$	- 55 ---- + 150								°C						

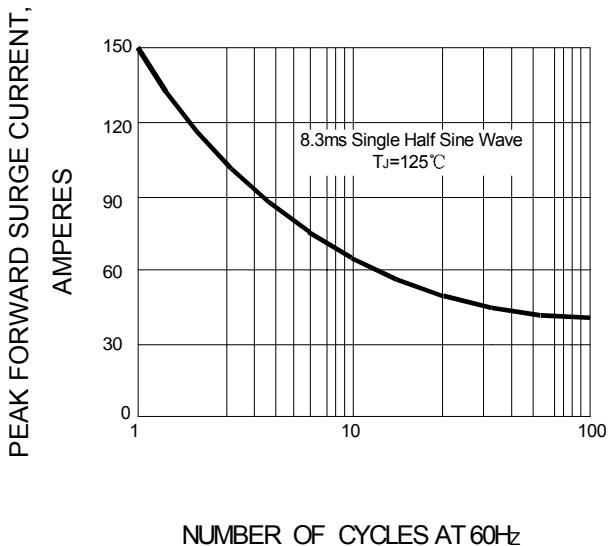
NOTE: 1. Pulse test: 300μs pulse width, 1% duty cycle.

2. Thermal resistance from junction to case.

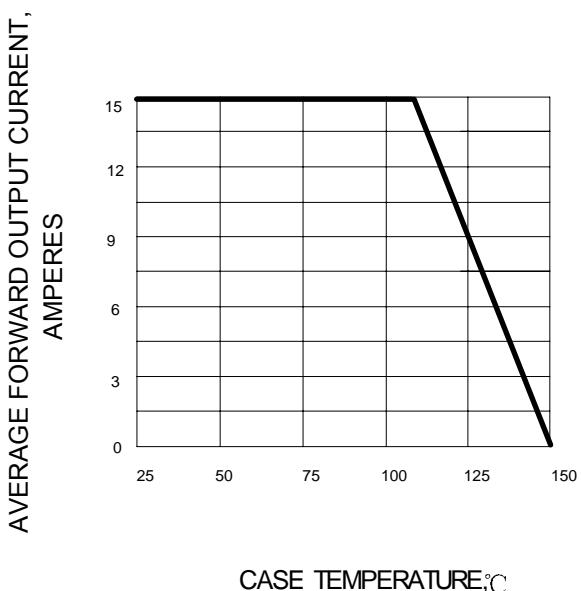
3.  $T_c=100^\circ C$

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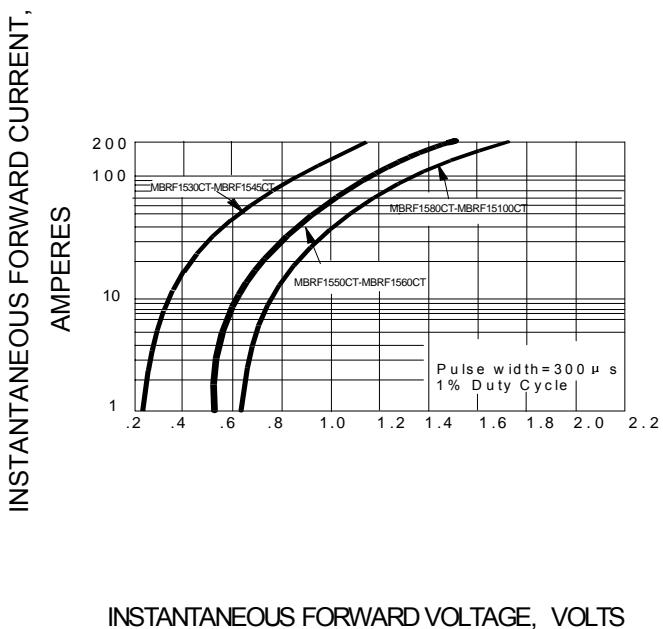
**FIG.1 – PEAK FORWARD SURGE CURRENT**



**FIG.2 – FORWARD DERATING CURVE**



**FIG.3 – TYPICAL FORWARD CHARACTERISTIC**



**FIG.4 – TYPICAL REVERSE CHARACTERISTIC**

